Unitized Semiconductor Devices - Page 1 of 1



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Inclosure Material:
Metal
Overall Length:
Between 0.170 inches and 0.210 inches
Terminal Length:
0.500 inches
Overall Diameter:
Between 0.208 inches and 0.230 inches
Function For Which Designed:
Amplifier
Electrode Internally-electrically Connected To Case:
Source
Component Name And Quantity:
2 transistor
Mounting Method:
Terminal
Terminal Circle Diameter:
0.100 inches
Features Provided:
Hermetically sealed case
Semiconductor Material:
Silicon all transistor
Voltage Rating In Volts Per Characteristic:
35.0 drain to gate voltage all transistor and 20.0 drain to source voltage all transistor
Current Rating Per Characteristic:
50.00 milliamperes source cutoff current of standard range all transistor
Power Rating Per Characteristic:
360.0 milliwatts small-signal input power, common-collector absolute all transistor
Maximum Operating Tempurature Per Measurement Point:
175.0 degrees celsius junction
Terminal Type And Quantity:
4 uninsulated wire lead
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0